

Characteristic			Symbol	Value	Unit
Source-Source Voltage			V _{SSS}	24	V
Gate-Source Voltage (Note 5)		V_{GSS}	±12	V	
Continuous Source Current @ T _A = +25°C (Note 6)	Steady State	$T_A = +25$ °C $T_A = +70$ °C	Is	6.0 4.8	А
Pulsed Source Current @ T _A = +25°C (Notes 6 & 7)			I _{SM}	20	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation @ T _A = +25°C (Note 6)	P_{D}	1.45	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 6)	$R_{ hetaJA}$	88.21	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

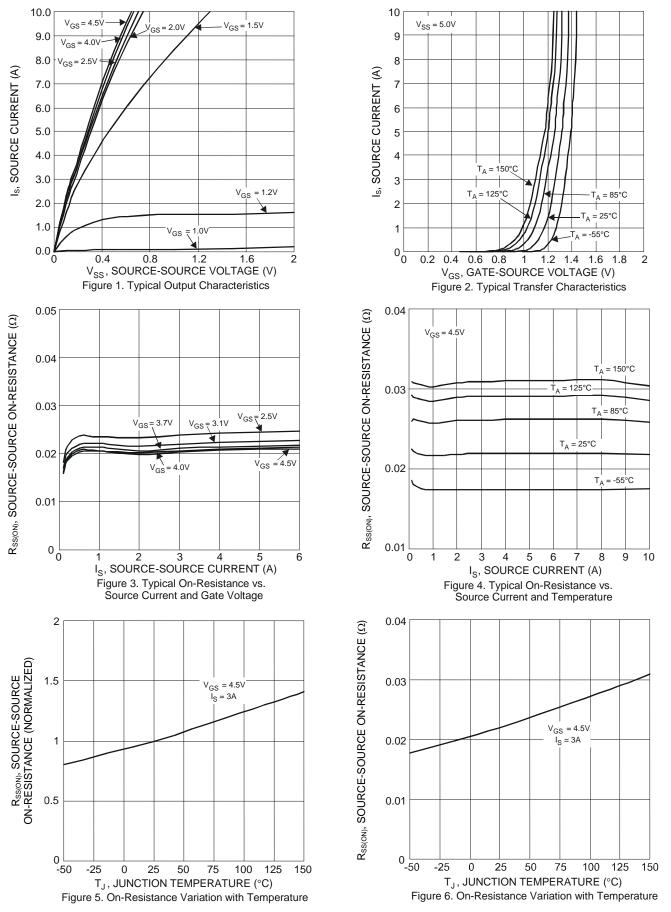
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Source to Source Breakdown Voltage T _J = +25°C	V _{(BR)SSS}	24	_	_	V	I _S = 1mA, V _{GS} = 0V, Test Circuit 1	
Zero Gate Voltage Source Current T _J = +25°C	I _{SSS}	_	_	1.0	μΑ	V _{SS} = 20V, V _{GS} = 0V, Test Circuit 1	
Gate-Body Leakage	I _{GSS}	_	_	±10	μΑ	V _{GS} = ±8V, V _{SS} = 0V, Test Circuit 2	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	0.5	_	1.3	V	V _{SS} = 10V, I _S = 1.0mA, Test Circuit 3	
		17	21.5	25.5	0	$V_{GS} = 6.5V$, $I_S = 3.0A$, Test Circuit 5	
	Rss(ON)	17.5	22	26		$V_{GS} = 4.5V$, $I_S = 3.0A$, Test Circuit 5	
Static Source-Source On-Resistance		18.5	23	27		$V_{GS} = 4.0V$, $I_S = 3.0A$, Test Circuit 5	
Static Source-Source On-Resistance		19	23.5	29	mΩ	$V_{GS} = 3.7V$, $I_S = 3.0A$, Test Circuit 5	
		19.5	24	33		$V_{GS} = 3.1V$, $I_S = 3.0A$, Test Circuit 5	
		21.5	27	40		V _{GS} = 2.5V, I _S = 3.0A, Test Circuit 5	
Forward Transfer Admittance	Y _{fs}	_	12	_	S	V _{SS} = 10V, I _S = 3.0A, Test Circuit 4	
Body Diode Forward Voltage	V _{F(S-S)}	_	0.7	1	V	I _F = 3.0A, V _{GS} = 0V, Test Circuit 6	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C _{iss}	_	2564	3333		$V_{SS} = 10V$, $V_{GS} = 0V$, $f = 1.0MHz$ Test Circuit 7	
Output Capacitance	Coss	_	197	275	pF		
Reverse Transfer Capacitance	Crss	_	183	260			
Total Gate Charge	Qg	_	29	37	nC	V _{GS} = 4.5V, V _{SS} = 10V, I _S = 6A Test Circuit 9	
Turn-On Delay Time	t _{D(ON)}	_	10	15	ns	$\begin{aligned} & V_{SS} = 10V, \\ & R_L = 3.33\Omega, \ I_S = 3.0A \\ & Test \ Circuit \ 8 \end{aligned}$	
Turn-On Rise Time	t _R	_	20	_	ns		
Turn-Off Delay Time	t _{D(OFF)}	_	75	110	ns		
Turn-Off Fall Time	t _F	_	29	_	ns		

Notes: 5. AEC-Q10

- 5. AEC-Q101 $\ensuremath{\text{V}_{\text{GS}}}$ maximum is ±9.6V.
- 6. Device mounted on FR-4 material with 1-inch 2 (6.45-cm 2), 2-oz.(0.071-mm thick) Cu.
- 7. Repetitive rating, pulse width limited by junction temperature.
- 8. Short duration pulse test used to minimize self-heating effect.
- 9. Guaranteed by design. Not subject to production testing.





DMN2023UCB4



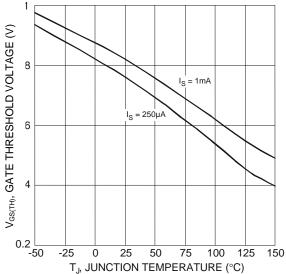


Figure 7. Gate Threshold Variation vs. Junction Temperature

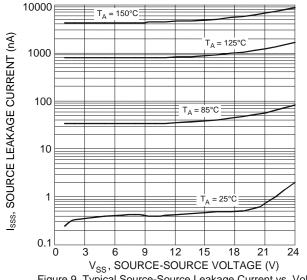
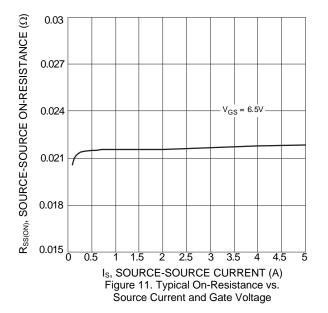
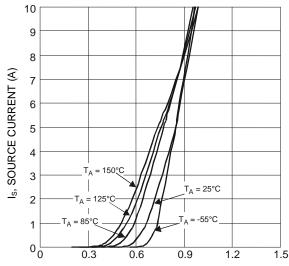


Figure 9. Typical Source-Source Leakage Current vs. Voltage





 V_{FSS} , FORWARD SOURCE-SOURCE VOLTAGE (V) Figure 8. Diode Forward Voltage vs. Current

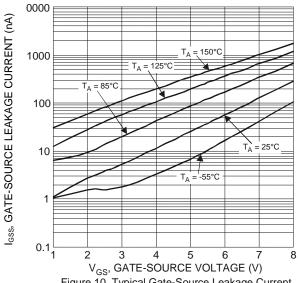
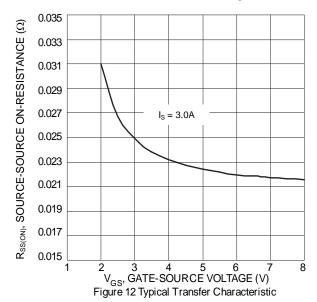
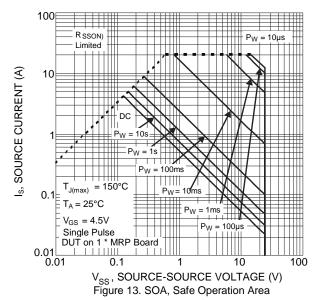


Figure 10. Typical Gate-Source Leakage Current vs. Gate-Source Voltage

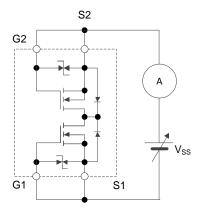




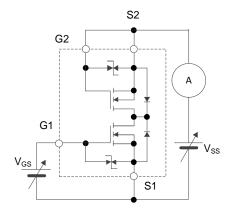




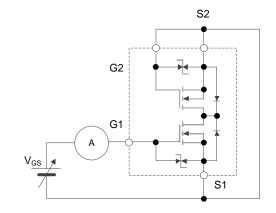
Test Circuits



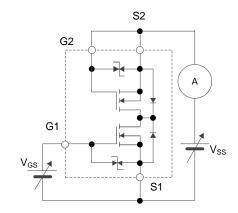
Test Circuit 1 Isss



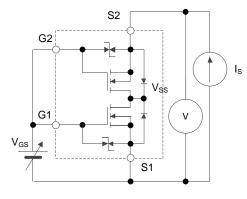
Test Circuit 3 $V_{\text{GS(OFF)}}$ When FET1 is measured, between GATE and SOURCE of FET2 are shorted.



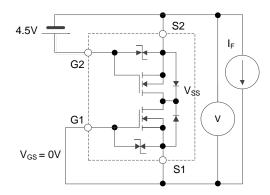
Test Circuit 2 I_{GSS}
When FET1 is measured, between GATE and SOURCE of FET2 are shorted.



 $\begin{array}{c} \text{Test Circuit 4 } |\, Y_{\text{fs}}| \\ \Delta I_{\text{S}} \! / \! \Delta V_{\text{GS}} \end{array}$



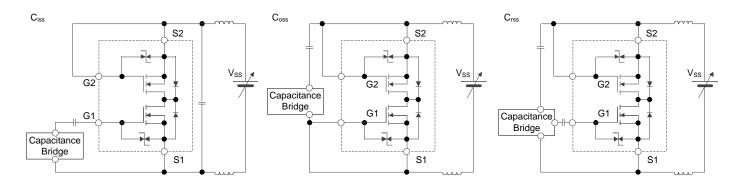
Test Circuit 5 R_{SS(ON)} V_{SS}/I_S



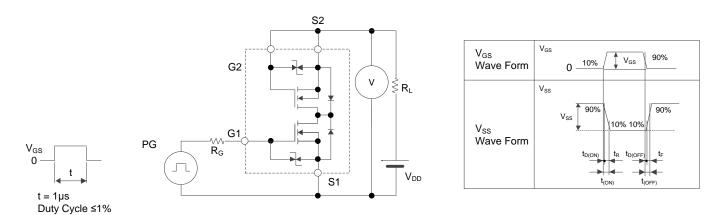
 $\label{eq:total_control} Test \ Circuit \ 6 \ V_{F(S\text{-}S)} \\ When \ FET1 \ is \ measured, \ FET2 \ is \ added \ V_{GS} \ +4.5 V.$



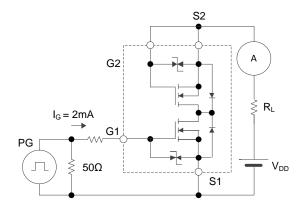
Test Circuits (Cont.)



Test Circuit 7



Test Circuit 8 $t_{D(ON)}$, t_{R} , $t_{D(OFF)}$, t_{F}



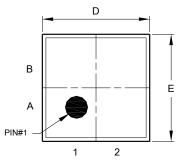
Test Circuit 9 Q_G

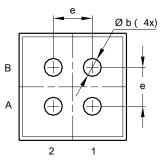


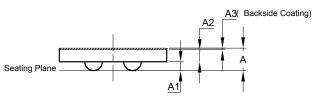
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

X1-WLB1818-4







X1-WLB1818-4					
Dim	Min	Max	Тур		
Α	0.3420	0.4080	0.3750		
A1	0.1350	0.1650	0.1500		
A2	0.1850	0.2150	0.2000		
A3	0.0220	0.0280	0.0250		
b	0.2700	0.3300	0.3000		
D	1.7800	1.8000	1.7900		
Е	1.7800	1.8000	1.7900		
е	0.650 BSC				
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

X1-WLB1818-4

$$\begin{array}{c|c} D (4x) & \stackrel{1}{\longrightarrow} C & \stackrel{2}{\longrightarrow} \\ A & \bigoplus & \bigoplus & C \\ B & \bigoplus & \bigoplus & C \end{array}$$

Dimensions	Value (in mm)	
С	0.65	
D	0.30	



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